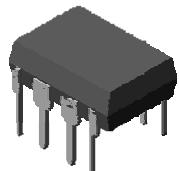


Semiconductor[http:// www.auk.co.kr](http://www.auk.co.kr)**SOP-8****DIP-8****ORDERING INFORMATION**

Product	Marking	Package
SN7103	SN7103	SOP-8
SN7103P	SN7103	DIP-8

▲ Marking Detail Information

SN7103(①)
YYWW(②)

① Device Code

② Week Code

Description

The SN7103 is a monolithic IC that includes one independent op-amp and another op-amp for which the non inverting input is wired to a 2.5V fixed Voltage Reference. This device is offering space and cost saving in many applications like power supply management or data acquisition systems.

OPERATIONAL AMPLIFIER

LOW INPUT OFFSET VOLTAGE : 1.0mV

LOW SUPPLY CURRENT : 350uA/op.(@ VCC = 5V)

MEDIUM BANDWIDTH (unity gain) : 0.9MHz

LARGE OUTPUT VOLTAGE SWING : 0V to (Vcc - 1.5V)

INPUT COMMON MODE VOLTAGE RANGE INCLUDES GROUND

WIDE POWER SUPPLY RANGE : 3 to 32V or (± 1.5 to ± 16 V)

VOLTAGE REFERENCE

FIXED OUTPUT VOLTAGE REFERENCE 2.5V

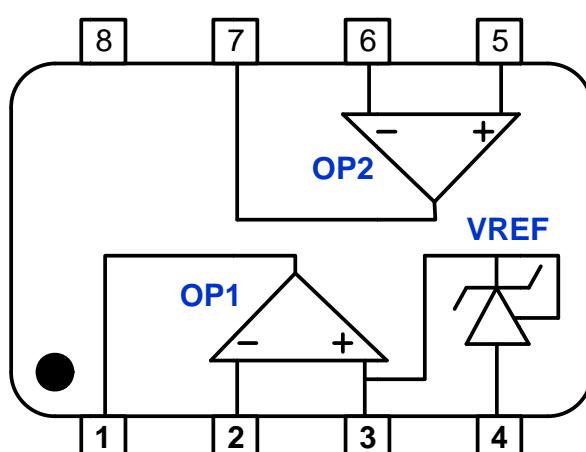
0.4% AND 1% VOLTAGE PRECISION

SINK CURRENT CAPABILITY : 1 to 100mA

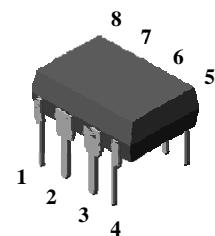
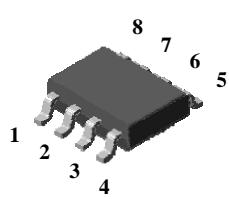
TYPICAL OUTPUT IMPEDANCE : 0.2Ω

Application

- ◆ Battery chargers
- ◆ AC to DC Power Supply

Block Diagram

◆ Pin connection



◆ Pin Configuration

No.	Name	Function
1	Output 1	OP-AMP 1 Output
2	Input 1 (-)	OP-AMP 1 Inverting Input
3	Input 1 (+)	OP-AMP 1 Non-Inverting Input
4	V _{EE}	GND or Negative Supply Voltage Input
5	Input 2 (+)	OP-AMP 2 Non-Inverting Input
6	Input 2 (-)	OP-AMP 2 Inverting Input
7	Output 2	OP-AMP 2 Output.
8	V _{CC}	Supply Voltage Input

◆ Absolute Maximum Ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit
DC Supply Voltage	V _{CC}	36	V
Differential Input Voltage	V _{id}	36	V
Input Voltage	V _i	-0.3 to +36	V
Maximum Junction Temperature	T _j	150	°C
Operating Junction Temperature Range	T _{opr}	-40 ~ +85	°C
Thermal Resistance	R _{thja}	175	°C / W
Storage Temperature Range	T _{stg}	-55 ~ +150	°C

◆ Electrical Characteristics (Ta = 25°C)

Parameter	Symbol	Min	Typ	Max	Unit
Total Supply Current, excluding current in the voltage reference Vcc = 5V, no load Tmin < Tamb < Tmax Vcc = 30V, no load Tmin < Tamb < Tmax	I _{CC}	-	0.7	1.2	mA

◆ Electrical characteristics

[Independent OP-AMP 2]

($V_{CC}=+5V$, $V_{EE}=\text{Ground}$, $V_o=1.4V$, $T_A=25^\circ\text{C}$; unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Offset Voltage	V_{io}	Ta = 25°C	-	1.0	4.0	mV
		Tmin. < Ta < Tmax	-	-	5.0	
Input Offset Voltage Drift	DV_{io}		-	7.0	-	uV/°C
Input Offset Current	I_{io}	Ta = 25°C	-	2.0	30	nA
		Tmin. < Ta < Tmax	-	-	50	
Input Bias Current	I_{ib}	Ta = 25°C	-	20	150	nA
		Tmin. < Ta < Tmax	-	-	200	
Large Signal Voltage Gain	A_{vd}	Vcc=15V, $R_L=2K$, $V_o=1.4V$ to 11.4V	50	100	-	V/mV
		Tmin. < Ta < Tmax	25	-	-	
Supply Voltage Rejection Ratio	SVR	Vcc=5V to 30V	65	100	-	dB
Input Common Mode Voltage Range	V_{icm}	Vcc=30V [Note 1]	0	-	Vcc-1.5	V
		Tmin. < Ta < Tmax	0	-	Vcc-2.0	
Common Mode Rejection Ratio	CMR	Ta = 25 °C	70	85	-	dB
		Tmin. < Ta < Tmax	60	-	-	
Output Source Current	I_{source}	Vcc=15V, $V_o=2V$, $Vid=1V$	20	40	-	mA
Short Circuit to Ground	I_O	Vcc=15V	-	40	60	mA
Output Sink Current	I_{sink}	Vcc=15V, $V_o=2V$, $Vid=-1V$	10	20	-	mA
High Level Output Voltage	V_{OH}	Vcc=30V, $R_L=10K$	27	28	-	V
		Tmin. < Ta < Tmax	27	-	-	
Low Level Output Voltage	V_{OL}	$RL=10K$	-	5	20	mV
		Tmin. < Ta < Tmax	-	-	20	
Slew Rate at Unity Gain	SR	$Vi=0.5V$ to $3V$, $Vcc=15V$, $R_L=2K$, $C_L=100pF$	0.2	0.4	-	V/us
Gain Bandwidth Product	GBP	Vcc=30V, $R_L=2k$, $C_L=100pF$, $f=100kHz$, $Vin=10mV$	0.5	0.9	-	MHz
Total Harmonic Distortion	THD	F=1kHz, $Av=20dB$, $R_L=2k$, $Vcc=30V$, $C_L=100pF$, $V_o=2V_{pp}$	-	0.02	-	%

Note 1 : The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is VCC -1.5V But either of both inputs can go to +36V without damage.

◆ Electrical characteristics

[Independent OP-AMP 1 with non-inverting input connected to the internal Vref]

($V_{CC}=+5V$, $V_{EE}=\text{Ground}$, $T_A=25^\circ\text{C}$; unless otherwise specified)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Input Offset Voltage	V_{io}	$T_a = 25^\circ\text{C}$	-	1.0	4.0	mV
		$T_{min.} < T_a < T_{max}$	-	-	5.0	
Input Offset Voltage Drift	DV_{io}	-	-	7.0	-	$\mu\text{V}/^\circ\text{C}$
Input Bias Current (negative input)	I_{ib}	-	-	20	-	nA
Large Signal Voltage Gain	A_{vd}	$V_{CC}=15V$, $R_L=2K$, $V_{ICM}=0V$	-	100	-	V/mV
Supply Voltage Rejection Ratio	SVR	$V_{CC}=5V \text{ to } 30V$ $V_{ICM}=0V$	65	100	-	dB
Output Source Current	I_{source}	$V_{CC}=15V$, $V_o=2V$, $V_{id}=1V$	20	40	-	mA
Short Circuit to Ground	I_O	$V_{CC}=15V$	-	40	60	mA
Output Sink Current	I_{sink}	$V_{CC}=15V$, $V_o=2V$, $V_{id}=-1V$	10	20	-	mA
High Level Output Voltage	V_{OH}	$V_{CC}=30V$, $R_L=10K$	27	28	-	V
		$T_{min.} < T_a < T_{max}$	27	-	-	
Low Level Output Voltage	V_{OL}	$R_L=10K$	-	5	20	mV
		$T_{min.} < T_a < T_{max}$	-	-	20	
Slew Rate at Unity Gain	SR	$V_i=0.5V \text{ to } 2V$, $V_{CC}=15V$ $R_L=2K$, $C_L=100\text{pF}$	0.2	0.4	-	$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP	$V_{CC}=30V$, $R_L=2k$, $C_L=100\text{pF}$, $f=100\text{kHz}$, $V_{in}=10\text{mV}$	0.5	0.9	-	MHz
Total Harmonic Distortion	THD	$F=1\text{kHz}$, $A_v=20\text{dB}$, $R_L=2k$, $V_{CC}=30V$, $C_L=100\text{pF}$, $V_o=2V_{pp}$	-	0.02	-	%

◆ Electrical characteristics

[Voltage Reference]

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Cathode Current	I_K	-	-	-	100	mA
Reference Input Voltage	V_{ref}	$T_a = 25^\circ C$	2.475	2.500	2.525	V
		$T_{min} < T_a < T_{max}$	2.450	2.500	2.550	
Reference Input Voltage Deviation Over Temperature Range	ΔV_{ref}	$V_{KA} = V_{ref}, I_K = 10\text{mA}, T_{min} < T_a < T_{max}$	-	7	30	mV
Minimum Cathode Current for Regulation	I_{min}	$V_{KA} = V_{ref}$	-	0.5	1.0	mA
Dynamic Impedance [note 1]	$ Z_{KA} $	$V_{KA} = V_{ref}, I_K = 1 \text{ to } 100\text{mA}, f < 1\text{kHz}$	-	0.2	0.5	Ω

Note 1 : the dynamic impedance is defined as $|Z_{KA}| = \Delta V_{KA} / \Delta I_K$

◆ Typical application circuit

Secondary Block

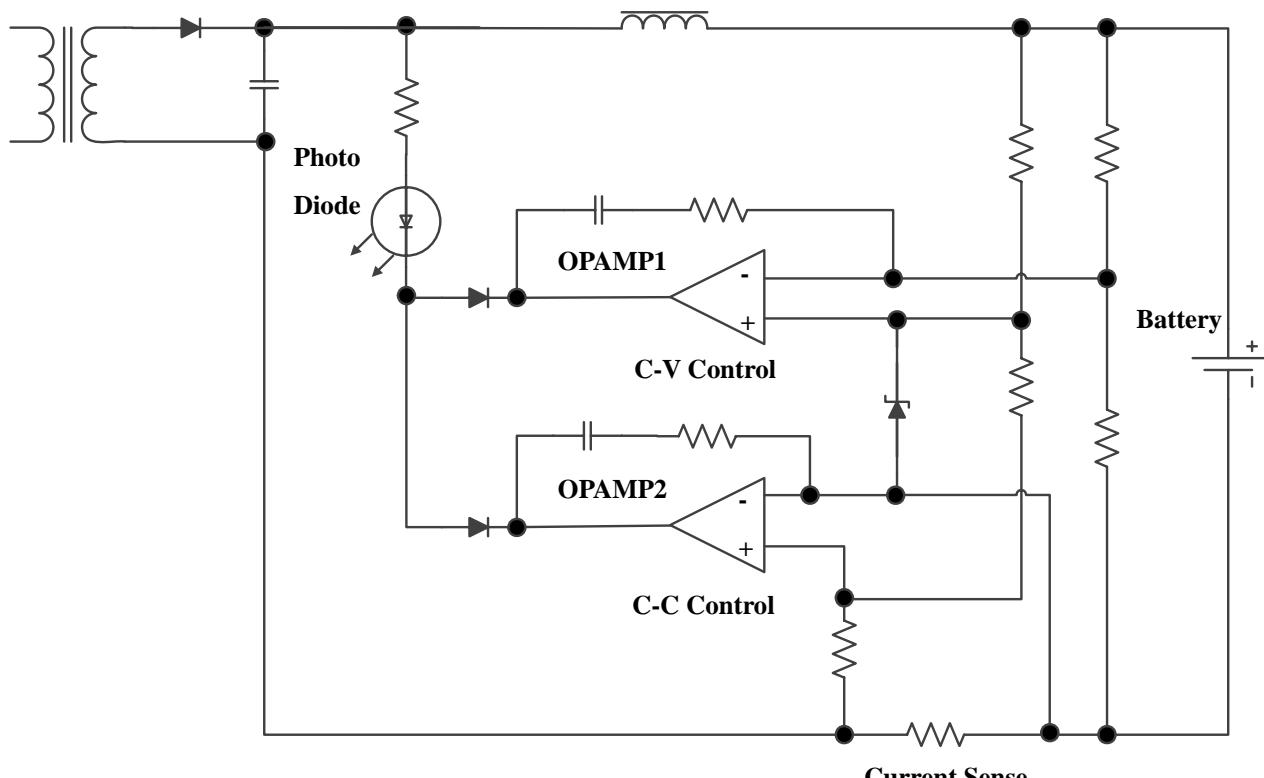
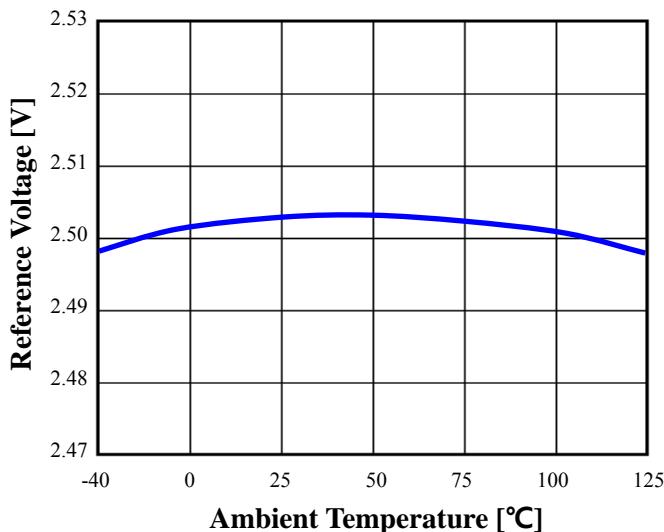
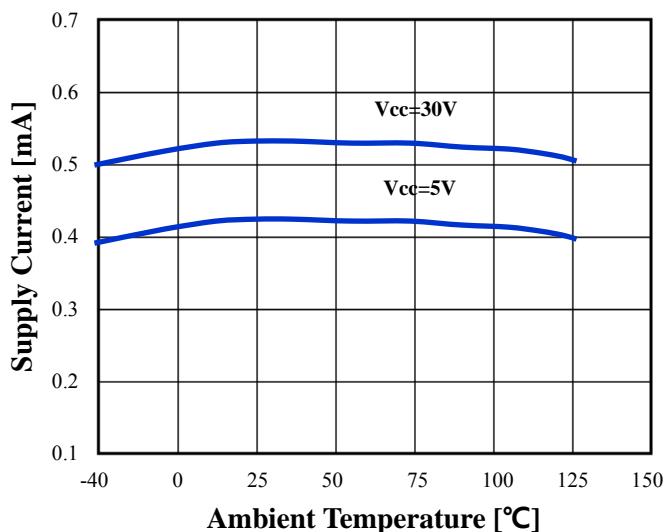
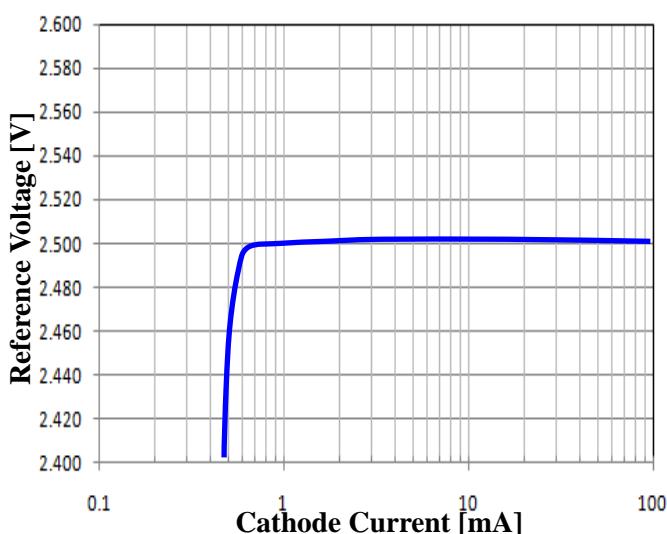
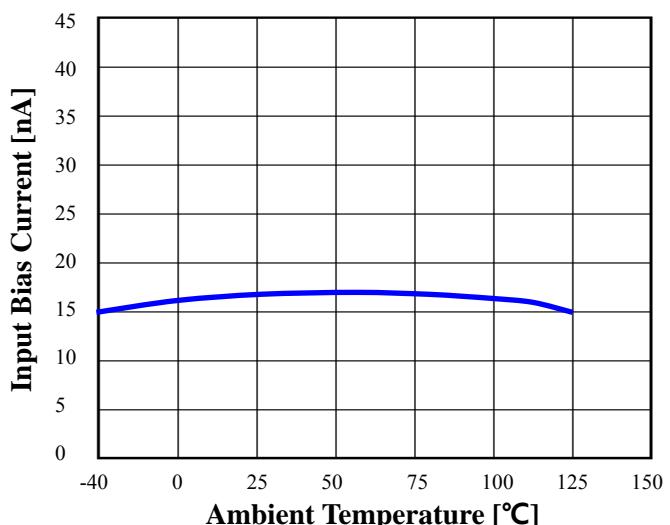
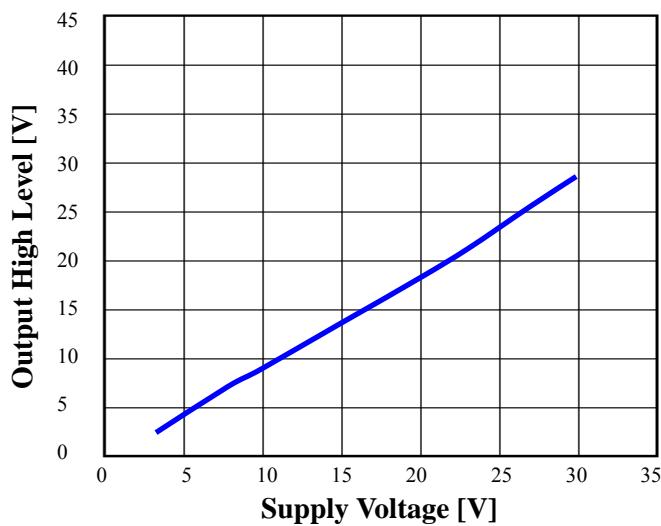
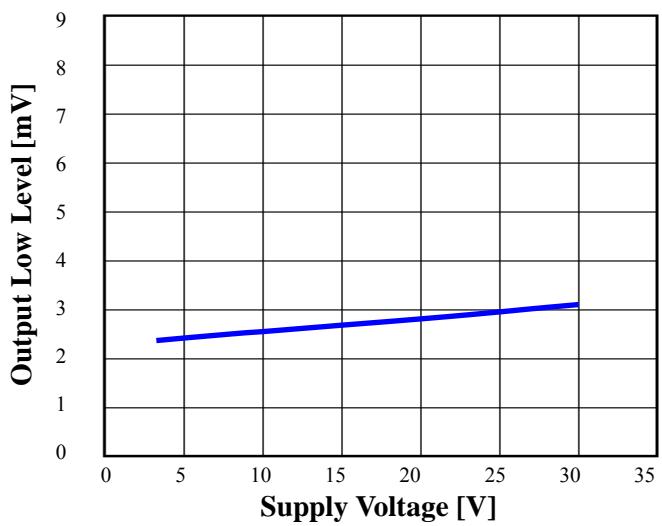
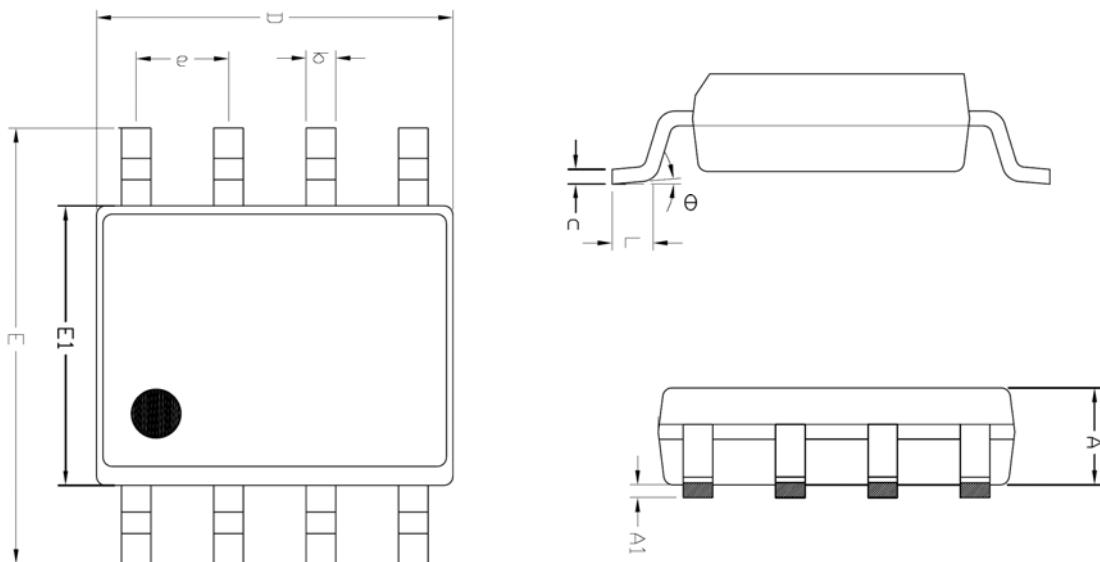
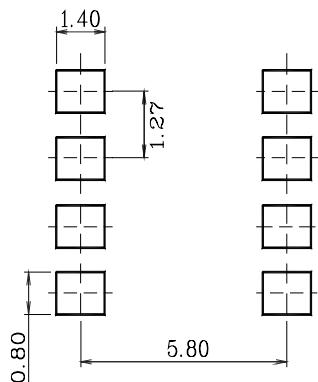
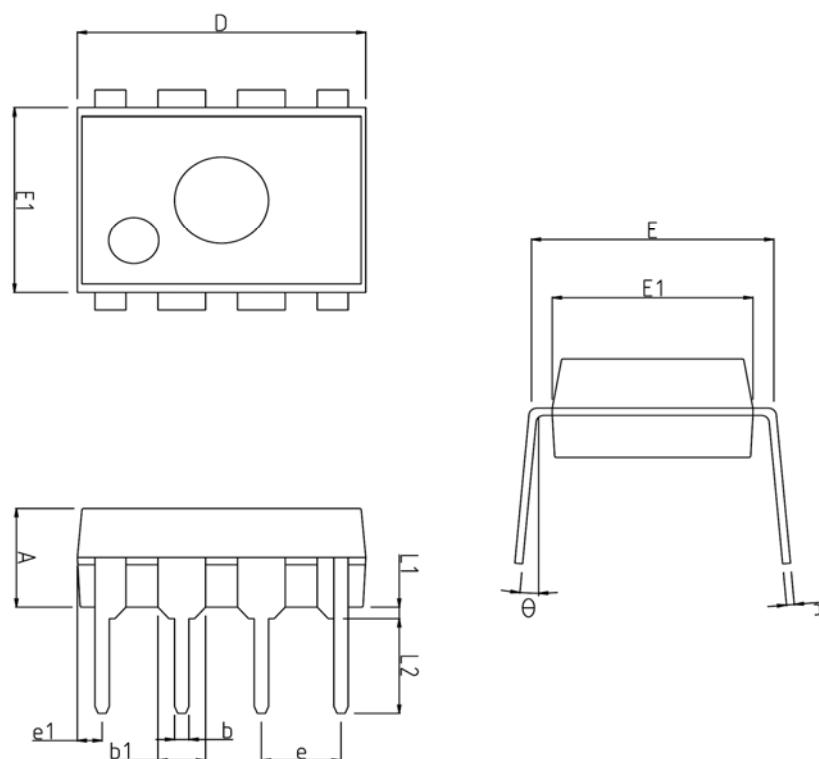


Fig.1 Reference Voltage vs. Ambient Temp.**Fig.2 Supply Current vs. Ambient Temp.****Fig.3 Reference Voltage vs. Cathode Current****Fig.4 Input Bias Current vs. Ambient Temp.****Fig.5 Output High Level vs. V_{CC}****Fig.6 Output Low Level vs. V_{CC}**

Outline Dimension (Unit : mm)


SYMBOL	MILLIMETER(mm)			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	1.245	—	1.445	
A1	0.125	0.175	0.275	
b	0.320	0.420	0.520	
c	0.170	0.220	0.270	
D	4.802	4.902	5.002	
E	5.870	6.020	6.170	
E1	3.761	3.861	3.961	
e	1.270 BSC			
L	0.462	0.562	0.662	
θ	0 °	—	8 °	

*** Recommend PCB solder land (Unit : mm)**


Outline Dimension (Unit : mm)


SYMBOL	MILLIMETERS			NOTE
	MINIMUM	NOMINAL	MAXIMUM	
A	3.20	3.40	3.60	
b	0.36	0.46	0.56	
b1	1.42	1.52	1.62	
c	0.20	0.25	0.35	
D	9.00	9.20	9.40	
E	7.37	7.62	7.87	
E1	6.20	6.40	6.60	
e	2.54 TYP			
e1	0.79 TYP			
L1	0.33	—	—	
L2	3.00	3.30	3.60	
θ	0°	—	15°	

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